

MILITARY SPECIFICATION
MICROCIRCUITS, DIGITAL,
TTL ARITHMETIC LOGIC UNITS/FUNCTION GENERATORS
MONOLITHIC SILICON

This specification is approved for use by all Departments and Agencies of the Department of Defense.

1. SCOPE

1.1 Scope. This specification covers the detail requirements for monolithic, silicon, TTL arithmetic logic units/function generators. Three product assurance classes and a choice of case outline/lead material and finish are provided and are reflected in the complete part number.

1.2 Part number. The part number shall be in accordance with MIL-M-38510.

1.2.1 Device type. The device type shall be as follows:

<u>Device type</u>	<u>Circuit</u>
01	Arithmetic logic unit/function generator
02	Lookahead carry generator

1.2.2 Device class. Device class shall be the product assurance level as defined in MIL-M-38510.

1.2.3 Case outline. The case outline shall be designated as follows:

<u>Outline letter</u>	<u>MIL-M-38510, appendix C, case outline</u>
E	D-2 (16-lead, 1/4" x 7/8", dual-in-line pack)
F	F-5 (16-lead, 1/4" x 3/8", flat pack)
J	D-3 (24-lead, 1/2" x 1-1/4", dual-in-line pack)
K	F-6 (24-lead, 3/8" x 5/8", flat pack)
L	F-7 (24-lead, 3/8" x 1/2", flat pack)
Z	F-8 (24-lead, 1/4" x 3/8", flat pack)

1.3 Absolute maximum ratings.

Supply voltage range	- - - - -	-0.5 Vdc to 7.0 Vdc
Input voltage range	- - - - -	-1.5 Vdc at -12 mA to 5.5 Vdc
Storage temperature range	- - - - -	-65°C to 150°C
Maximum power dissipation, P_D	1/	795 mWdc
Lead temperature (soldering 10 seconds)	- - -	300°C
Thermal resistance, junction to case	- - -	$\theta_{JC} = \begin{cases} 0.04^\circ\text{C}/\text{mW} & \text{for flat pack} \\ 0.02^\circ\text{C}/\text{mW} & \text{for dual-in-line pack} \end{cases}$
Junction temperature	- - - - -	$T_J = 175^\circ\text{C}$

1/ Shall withstand the added P_D due to short circuit test (e.g., I_{OS}).

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Rome Air Development Center, RADC (RBRD), Griffiss AFB, NY 13441, by using the self-addressed Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.

1.4 Recommended operating conditions.

Supply voltage - - - - - 4.5 Vdc minimum to 5.5 Vdc maximum
Minimum high-level input voltage - - - 2.0 Vdc
Maximum low-level input voltage - - - 0.8 Vdc
Normalized fanout (each output)
Logical low level - - - - - 10 maximum
Logical high level - - - - - 20 maximum 1/
Ambient operating temperature range - - -55°C to 125°C

2. APPLICABLE DOCUMENT.

2.1 Issues of documents. The following document, of the issue in effect on date of invitation for bids or request for proposal, forms a part of this specification to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

(Copies of specifications, standards, drawings, and publications required by suppliers in connection with specific procurement functions should be obtained from the procuring activity or as directed by the contracting officer.)

3. REQUIREMENTS.

3.1 Detail specifications. The individual item requirements shall be in accordance with MIL-M-38510, and as specified herein. In the event of conflict between MIL-M-38510 and this detail specification, this detail specification shall govern.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510, and herein.

3.2.1 Terminal connections and logic diagrams. The terminal connections and logic diagrams shall be as specified on figures 1 and 2.

3.2.2 Truth tables and logic equations. The truth tables and logic equations shall be as specified on figure 3.

3.2.3 Schematic circuits. Schematic circuits shall be submitted to the preparing activity prior to inclusion of a manufacturer's device in this specification and shall be submitted to the qualifying activity as a prerequisite for qualification. All manufacturers' schematics shall be maintained and available upon request.

3.2.4 Case outlines. The case outlines shall be as specified in 1.2.3.

3.3 Lead material and finish. The lead material and finish shall be in accordance with MIL-M-38510 (See 6.5).

3.4 Electrical performance characteristics. The electrical performance characteristics are specified in table I, and apply over the full recommended ambient operating temperature range, unless otherwise specified.

3.5 Rebonding. Rebonding shall be in accordance with MIL-M-38510.

1/ A fanout of 20 normalized loads is provided to facilitate connection of unused inputs to used inputs.

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/	Device type	Limits		
				Min	Max	Units
High-level output voltage	V _{OH}	V _{CC} = 4.5 V; V _{IL} = 0.8 V; V _{IN} = 2.0 V; I _{OH} = -800 μ A	01, 02	2.4		Volts
Low-level output voltage	V _{OL}	V _{CC} = 4.5 V; V _{IL} = 0.8 V; V _{IH} = 2.0 V; I _{OL} = 16 mA	01, 02		0.4	Volts
Input diode clamp	V _{IC}	V _{CC} = 5.5 V; I _{IN} = -12 mA T _A = 25°C	01, 02		-1.5	Volts
Low-level input current at M input	I _{IL1}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	01	-0.7	-1.6	mA
Low-level input current at B input	I _{IL2}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	01	-2.1	-4.8	mA
Low-level input current at S ₀ or S ₃ input	I _{IL3}	V _{CC} = 5.5 V; V _{IN} = 0.4 2/	01	-2.8	-6.4	mA
Low-level input current at S ₁ or S ₂	I _{IL4}	V _{CC} = 5.5 V; V _{IN} = 0.4 V; A ₀ , A ₁ , A ₂ , A ₃ = 5.5 V 3/	01	-2.8	-6.4	mA
Low-level input current at C _n input	I _{IL5}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 3/	01	-3.5	-8.0	mA
Low-level input current at A input	I _{IL6}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	01	-1.4	-3.2	mA
Low-level input current at G ₁ input	I _{IL7}	V _{CC} = 5.5 V; V _{IN} = 0.4 V, C _n = GND 2/	02	-5.6	-16.0	mA
Low-level input current at P ₁ input	I _{IL8}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	02	-2.8	-8.0	mA
Low-level input current at G ₀ input	I _{IL9}	V _{CC} = 5.5 V; V _{IN} = 0.4 V, C _n = GND 2/	02	-4.9	-14.0	mA
Low-level input current at P ₀ input	I _{IL10}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	02	-2.8	-8.0	mA
Low-level input current at G ₃ input	I _{IL11}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	02	-2.8	-8.0	mA
Low-level input current at P ₃ input	I _{IL12}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	02	-1.4	-4.0	mA
Low-level input current at C _n input	I _{IL13}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	02	-0.7	-2.0	mA
Low-level input current at G ₂ input	I _{IL14}	V _{CC} = 5.5 V; V _{IN} = 0.4 V, C _n = GND 2/	02	-4.9	-14.0	mA
Low-level input current at P ₂ input	I _{IL15}	V _{CC} = 5.5 V; V _{IN} = 0.4 V 2/	02	-2.1	-6.0	mA
High-level input current at M input	I _{IH1}	V _{CC} = 5.5 V; V _{IN} = 2.4 V 3/	01		40	μ A
High-level input current at A or B input	I _{IH2}	V _{CC} = 5.5 V; V _{IN} = 2.4 V 3/	01		120	μ A
High-level input current at S ₀ or S ₃ input	I _{IH3}	V _{CC} = 5.5 V; V _{IN} = 2.4 V 3/	01		160	μ A
High-level input current at S ₁ or S ₂ input	I _{IH4}	V _{CC} = 5.5 V; V _{IN} = 2.4 V; B ₀ , B ₁ , B ₂ , B ₃ = 5.5 V 3/	01		160	μ A
High-level input current at C _n input	I _{IH5}	V _{CC} = 5.5 V; V _{IN} = 2.4 V 2/	01		200	μ A
High-level input current at M input	I _{IH6}	V _{CC} = 5.5 V; V _{IN} = 5.5 V 3/	01		100	μ A
High-level input current at A or B input	I _{IH7}	V _{CC} = 5.5 V; V _{IN} = 5.5 V 3/	01		300	μ A
High-level input current at S ₀ or S ₃ input	I _{IH8}	V _{CC} = 5.5 V; V _{IN} = 5.5 V 3/	01		400	μ A
High-level input current at S ₁ or S ₂ input	I _{IH9}	V _{CC} = 5.5 V; V _{IN} = 5.5 V; B ₀ , B ₁ , B ₂ , B ₃ = 5.5 V 3/	01		400	μ A

See footnotes at end of table I.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/	Device type	Limits		
				Min	Max	Units
High-level input current at C_n input	I _{IH10}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 2/$	01		500	μA
High-level input current at \bar{G} input	I _{IH11}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V};$ $C_n = 5.5 \text{ V } 3/$	02		400	μA
High-level input current at \bar{P}_1 input	I _{IH12}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V } 3/$	02		200	μA
High-level input current at \bar{G}_0 input	I _{IH13}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V};$ $C_n = 5.5 \text{ V } 3/$	02		350	μA
High-level input current at \bar{P}_0 input	I _{IH14}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V } 3/$	02		200	μA
High-level input current at \bar{G}_3 input	I _{IH15}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V } 3/$	02		200	μA
High-level input current at \bar{P}_3 input	I _{IH16}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V } 3/$	02		100	μA
High-level input current at C_n input	I _{IH17}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V } 3/$	02		70	μA
High-level input current at \bar{G}_2 input	I _{IH18}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V};$ $C_n = 5.5 \text{ V } 3/$	02		350	μA
High-level input current at \bar{P}_2 input	I _{IH19}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 2.4 \text{ V } 3/$	02		150	μA
High-level input current at \bar{G}_1 input	I _{IH20}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V};$ $C_n = 5.5 \text{ V } 3/$	02		800	μA
High-level input current at \bar{P}_1 input	I _{IH21}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 3/$	02		400	μA
High-level input current at G_0 input	I _{IH22}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V};$ $C_n = 5.5 \text{ V } 3/$	02		700	μA
High-level input current at \bar{P}_0 input	I _{IH23}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 3/$	02		400	μA
High-level input current at \bar{G}_3 input	I _{IH24}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 3/$	02		400	μA
High-level input current at \bar{P}_3 input	I _{IH25}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 3/$	02		200	μA
High-level input current at C_n input	I _{IH26}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 3/$	02		160	μA
High-level input current at \bar{G}_2 input	I _{IH27}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V};$ $C_n = 5.5 \text{ V } 3/$	02		700	μA
High-level input current at \bar{P}_2 input	I _{IH28}	$V_{CC} = 5.5 \text{ V}; V_{IN} = 5.5 \text{ V } 3/$	02		300	μA
Short-circuit output current at \bar{G} output	I _{OS1}	$V_{CC} = 5.5 \text{ V}; S_3, \bar{A}_3, \bar{B}_3 =$ $5.5 \text{ V } 3/ 4/$	01	-20	-55	mA
Short-circuit output current at C_{n+4} output	I _{OS2}	$V_{CC} = 5.5 \text{ V } 3/ 4/$	01	-20	-55	mA
Short-circuit output current at \bar{F}, \bar{F}_0 thru \bar{F}_3 outputs	I _{OS3}	$V_{CC} = 5.5 \text{ V } 2/ 4/$	01	-20	-55	mA
Short-circuit output current	I _{OS4}	$V_{CC} = 5.5 \text{ V}; V_{IL} = \text{GND};$ $V_{IN} = 5.5 \text{ V } 4/$	02	-40	-100	mA
Collector cutoff current at $A = B$ output	I _{CEX}	$V_{CC} = 4.5 \text{ V}; V_{(A=B)} = 5.5 \text{ V};$ all input = 2.0 V	01		250	μA
Low-level supply current	I _{ICCL1}	$V_{CC} = 5.5 \text{ V}; V_{IL} = 0 \text{ V};$ $V_{IH} = 5.5 \text{ V}$	01		127	mA
	I _{ICCL2}	$V_{CC} = 5.5 \text{ V}; V_{IL} = 0 \text{ V};$ $V_{IH} = 5.5 \text{ V}$	02		65	mA
High level supply current	I _{ICCH1}	$V_{CC} = 5.5 \text{ V}; V_{IL} = 0 \text{ V};$ $V_{IH} = 5.5 \text{ V}$	01		135	mA
	I _{ICCH2}	$V_{CC} = 5.5 \text{ V}; V_{IL} = 0 \text{ V};$ $V_{IH} = 5.5 \text{ V}$	02		55	mA

See footnotes at end of table I.

TABLE I. Electrical performance characteristics - Continued.

MIL-M-38510/11C

Test	Symbol	Conditions 1/	Device type	Limits		Unit
				Min	Max	
Propagation delay times, high-to-low level output: 5/						
\bar{A}_i or \bar{B}_i to any \bar{F} sum mode	t_{PHL1}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	46	ns
\bar{A}_i or \bar{B}_i to any \bar{F} diff mode	t_{PHL2}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	49	ns
\bar{A}_i or \bar{B}_i to \bar{P} sum mode	t_{PHL3}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	40	ns
\bar{A}_i or \bar{B}_i to \bar{P} diff mode	t_{PHL4}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	40	ns
\bar{A}_i or \bar{B}_i to \bar{G} sum mode	t_{PHL5}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	30	ns
\bar{A}_i or \bar{B}_i to \bar{G} diff mode	t_{PHL6}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	40	ns
C_n to any \bar{F} sum mode	t_{PHL7}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	25	ns
\bar{A}_i or \bar{B}_i to $A = B$ diff mode	t_{PHL8}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	76	ns
C_n to C_{n+4} sum mode	t_{PHL9}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	30	ns
C_n to C_{n+4} diff mode	t_{PHL10}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	30	ns
\bar{A}_i or \bar{B}_i to C_{n+4} sum mode	t_{PHL11}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	41	ns
\bar{A}_i or \bar{B}_i to C_{n+4} diff mode	t_{PHL12}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	50	ns
\bar{A}_i or \bar{B}_i to any \bar{F} logic mode	t_{PHL13}	$V_{CC} = 5.0 \text{ V}$ See figure 4 logic mode test table	01	7	49	ns
Propagation delay times, low-to-high level output: 5/						
\bar{A}_i or \bar{B}_i to any \bar{F} sum mode	t_{PLH1}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	60	ns
\bar{A}_i or \bar{B}_i to any \bar{F} diff mode	t_{PLH2}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	69	ns
\bar{A}_i or \bar{B}_i to \bar{P} sum mode	t_{PLH3}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	27	ns
\bar{A}_i or \bar{B}_i to \bar{P} diff mode	t_{PLH4}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	40	ns
\bar{A}_i or \bar{B}_i to \bar{G} sum mode	t_{PLH5}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	27	ns
\bar{A}_i or \bar{B}_i to \bar{G} diff mode	t_{PLH6}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	40	ns
C_n to any \bar{F} sum mode	t_{PLH7}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	27	ns
\bar{A}_i or \bar{B}_i to $A = B$ diff mode	t_{PLH8}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	80	ns
C_n to C_{n+4} sum mode	t_{PLH9}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	28	ns
C_n to C_{n+4} diff mode	t_{PLH10}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	28	ns
\bar{A}_i or \bar{B}_i to C_{n+4} sum mode	t_{PLH11}	$V_{CC} = 5.0 \text{ V}$ See figure 4 sum mode test table	01	7	50	ns
\bar{A}_i or \bar{B}_i to C_{n+4} diff mode	t_{PLH12}	$V_{CC} = 5.0 \text{ V}$ See figure 4 diff mode test table	01	7	50	ns
\bar{A}_i or \bar{B}_i to any \bar{F} logic mode	t_{PLH13}	$V_{CC} = 5.0 \text{ V}$ See figure 4 logic mode test table	01	7	69	ns

See footnotes at end of table I.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/	Device type	Limits		
				Min	Max	Units
Propagation delay times, high-to-low level output: 6/						
C _n to C _{n+X} , C _{n+Y} , C _{n+Z}	t _{PHL1}	V _{CC} = 5.0 V; \bar{P}_0 , \bar{P}_1 , \bar{P}_2 = GND; \bar{G}_0 , \bar{G}_1 , \bar{G}_2 = 2.4 V	02	6	35	ns
\bar{P}_0 , \bar{P}_1 , or \bar{P}_2 to C _{n+X} , C _{n+Y} , C _{n+Z}	t _{PHL2}	P _i = GND; C _n , \bar{G}_0 , \bar{G}_1 , \bar{G}_2 = V _{CC} = 5.0 V	02	3	32	ns
\bar{G}_0 , \bar{G}_1 , or \bar{G}_2 to C _{n+Y} , C _{n+X} , C _{n+Z}	t _{PHL3}	\bar{G}_i = 2.4 V; C _n , \bar{P}_0 , \bar{P}_1 , \bar{P}_2 = GND, V _{CC} = 5.0 V 7/	02	3	32	ns
\bar{P}_1 , \bar{P}_2 , or \bar{P}_3 to \bar{G} or \bar{P}	t _{PHL4}	V _{CC} = 5.0 V; \bar{P}_1 = GND; C _n , \bar{G}_0 , \bar{G}_1 , \bar{G}_2 , \bar{G}_3 = 2.4 V 7/	02	3	35	ns
\bar{G}_0 , \bar{G}_1 , \bar{G}_2 , or \bar{G}_3 to \bar{G}	t _{PHL5}	V _{CC} = 5.0 V; G _i = 2.4 V; \bar{P}_1 , \bar{P}_2 , \bar{P}_3 = GND 7/	02	3	35	ns
\bar{P}_0 , \bar{P}_1 , \bar{P}_2 , or \bar{P}_3 to \bar{P}	t _{PHL6}	\bar{P}_i = GND 7/	02	3	35	ns
Propagation delay times, low-to-high level output: 6/						
C _n to C _{n+X} , C _{n+Y} , C _{n+Z}	t _{PLH1}	V _{CC} = 5.0 V; \bar{P}_0 , \bar{P}_1 , \bar{P}_2 = GND; \bar{G}_0 , \bar{G}_1 , \bar{G}_2 = 2.4 V	02	6	29	ns
\bar{P}_0 , \bar{P}_1 , or P_2 to C _{n+X} , C _{n+Y} , C _{n+Z}	t _{PLH2}	V _{CC} = 5.0 V; C _n , \bar{G}_0 , \bar{G}_1 , \bar{G}_2 , G = 2.4 V; P _i = GND 7/	02	3	25	ns
\bar{G}_0 , \bar{G}_1 , or \bar{G}_2 to C _{n+X} , C _{n+Y} , C _{n+Z}	t _{PLH3}	V _{CC} = 5.0 V; C _n , \bar{P}_0 , \bar{P}_1 , \bar{P}_2 = GND; \bar{G}_i = 2.4 V 7/	02	3	25	ns
\bar{P}_1 , \bar{P}_2 , or \bar{P}_3 to \bar{G} or \bar{P}	t _{PLH4}	V _{CC} = 5.0 V; C _n , \bar{G}_0 , \bar{G}_1 , \bar{G}_2 , \bar{G}_3 = 2.4 V; P _i = GND 7/	02	3	26	ns
\bar{G}_0 , \bar{G}_1 , \bar{G}_2 , or \bar{G}_3 to \bar{G}	t _{PLH5}	V _{CC} = 5.0 V; \bar{P}_1 , \bar{P}_2 , \bar{P}_3 = GND; \bar{G}_i = 2.4 V 7/	02	3	26	ns
\bar{P}_0 , \bar{P}_1 , \bar{P}_2 , or \bar{P}_3 to \bar{P}	t _{PLH6}	V _{CC} = 5.0 V; \bar{P}_i = GND 7/	02	3	26	ns

NOTES:

- 1/ Condition of inputs specified in table III.
- 2/ All unspecified inputs at 5.5 V.
- 3/ All unspecified inputs at 0 V.
- 4/ Not more than one output should be shorted at a time.
- 5/ In \bar{A}_i and \bar{B}_i , i = 0, 1, 2, 3.
- 6/ In \bar{G}_i and \bar{P}_i , i = 0, 1, 2, or 3.
- 7/ If not under test.

3.6 Electrical test requirements. Electrical test requirements shall be as specified in table III for the applicable device type and device class. The subgroups of table III which constitute the minimum electrical test requirements for screening, qualification, and quality conformance by device class are specified in table II. (subgroups 7 and 8 testing requires only a summary of attributes data.)

TABLE II. Electrical test requirements.

MIL-STD-883 test requirement	Subgroups (see table III)		
	Class S devices	Class B devices	Class C devices
Interim electrical parameters (Pre Burn-In) (method 5004)	1	1	None
Final electrical test parameters (method 5004)	1*, 2, 3, 7, 9, 10, 11	1*, 2, 3, 7, 9	1, 7
Group A test requirements (method 5005)	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3, 7, 9	1, 2, 3, 7, 9
Group C and D end point electrical parameters (method 5005)	1, 2, 3	1, 2, 3	1
Additional electrical subgroups for Group C periodic inspections	None	10, 11	10, 11

* PDA applies to subgroup 1 (see 4.3c).

3.7 Marking. Marking shall be in accordance with MIL-M-38510 and 1.2. At the option of the manufacturer, the country of origin may be omitted from the body of the microcircuit, but shall be retained on the initial container.

3.8 Microcircuit group assignment. The devices covered by this specification shall be in microcircuit group number 4 (see MIL-M-38510 Appendix E).

4. PRODUCT ASSURANCE PROVISIONS

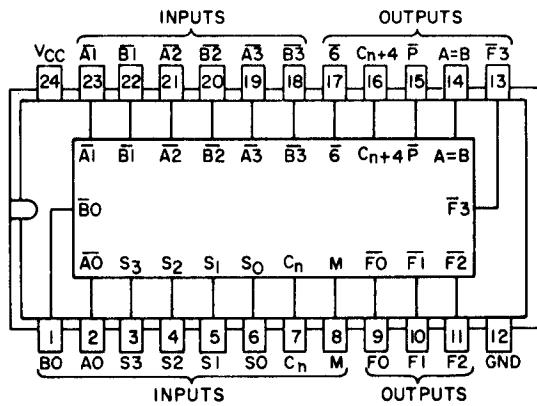
4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-M-38510 and Method 5005 of MIL-STD-883, except as modified herein.

4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, and D inspections (see 4.4.1, 4.4.2, and 4.4.3).

Pin designations

Designation	Pin nos.	Function
$\bar{A}_3, \bar{A}_2, \bar{A}_1, \bar{A}_0$	19, 21, 23, 2	Word A inputs
$\bar{B}_3, \bar{B}_2, \bar{B}_1, \bar{B}_0$	18, 20, 22, 1	Word B inputs
S_3, S_2, S_1, S_0	3, 4, 5, 6	Function-select inputs
C_n	7	Inv. carry input
M	8	Mode control input
$\bar{F}_3, \bar{F}_2, \bar{F}_1, \bar{F}_0$	13, 11, 10, 9	Function outputs
$A = B$	14	Comparator output
\bar{P}	15	Carry propagate output
C_{n+4}	16	Inv. carry output
\bar{G}	17	Carry generate output
V _{CC}	24	Supply voltage
GND	12	Ground

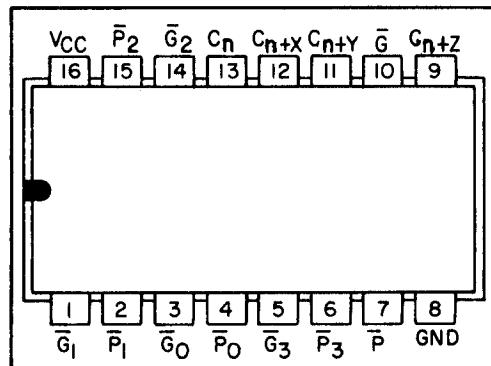
Cases J, K, L and Z

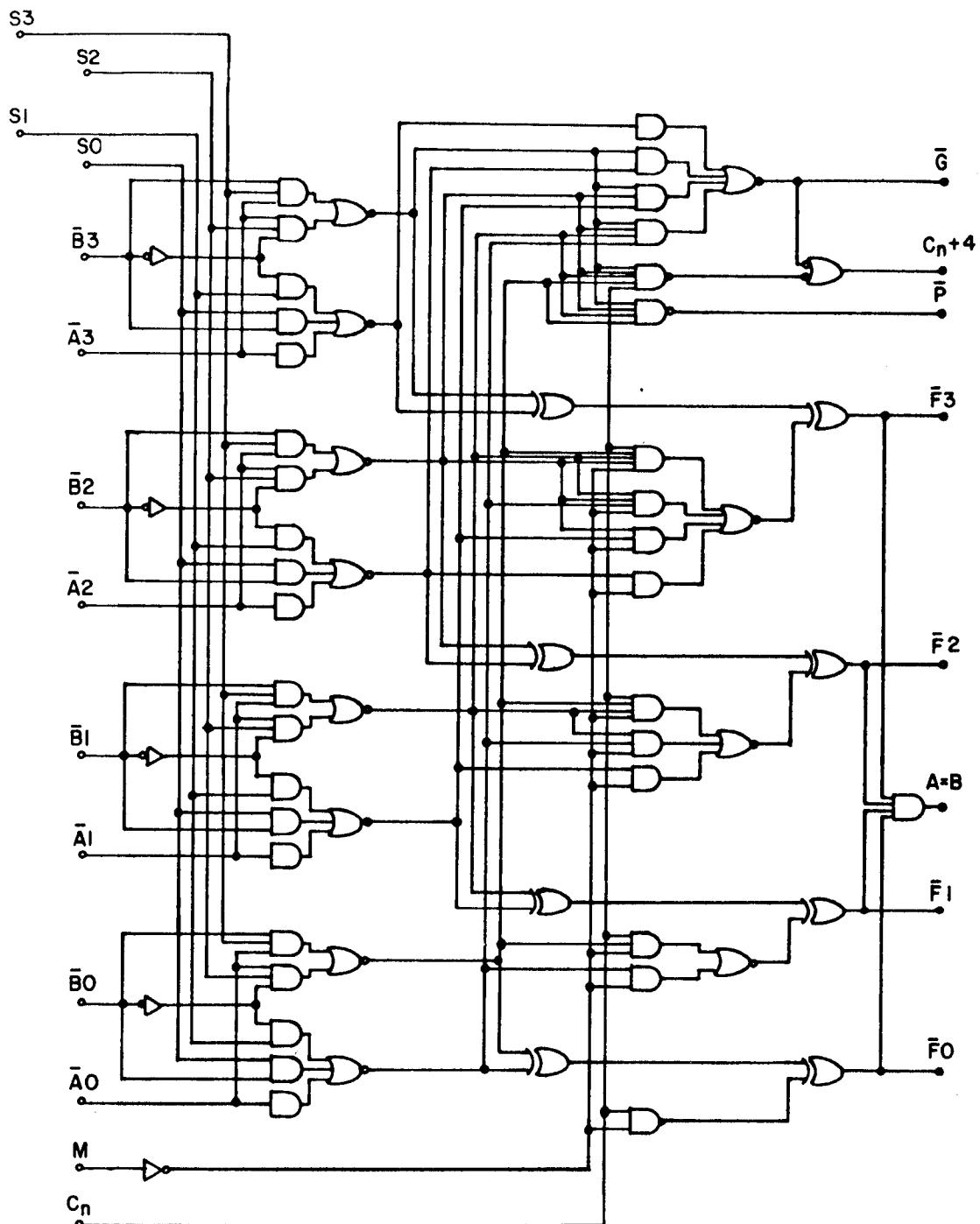
Device type 01

Pin designations

Designation	Pin nos.	Function
C_n	13	Carry input
$\bar{G}_0, \bar{G}_1, \bar{G}_2, \bar{G}_3$	3, 1, 14, 5	Carry generate input
$\bar{P}_0, \bar{P}_1, \bar{P}_2, \bar{P}_3$	4, 2, 15, 6	Carry propagate input
$C_{n+x}, C_{n+y}, C_{n+z}$	12, 11, 9	Carry output
\bar{G}	10	Carry generate output
\bar{P}	7	Carry propagate output

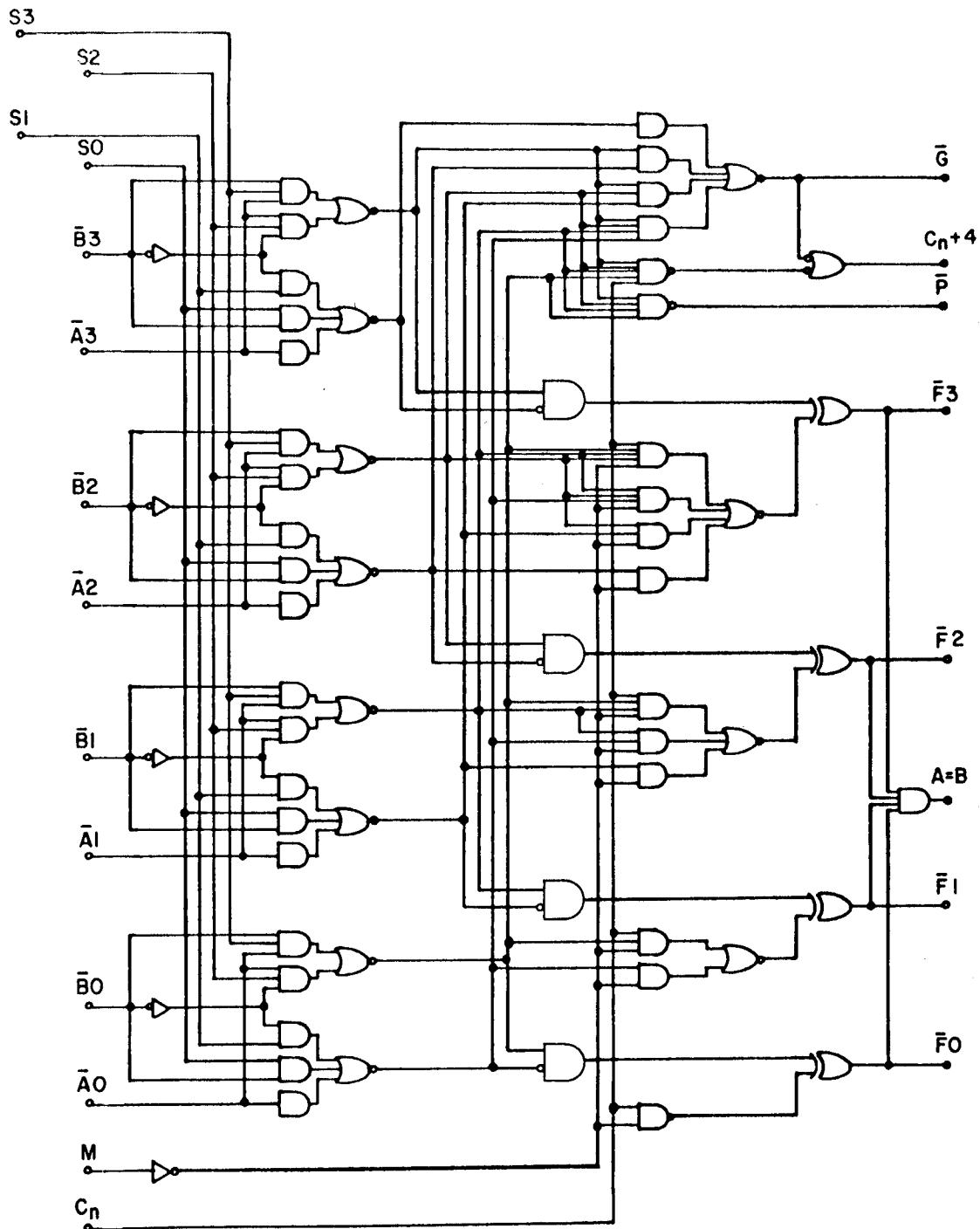
Cases E and F

Device type 02FIGURE 1. Terminal connections and pin designations.



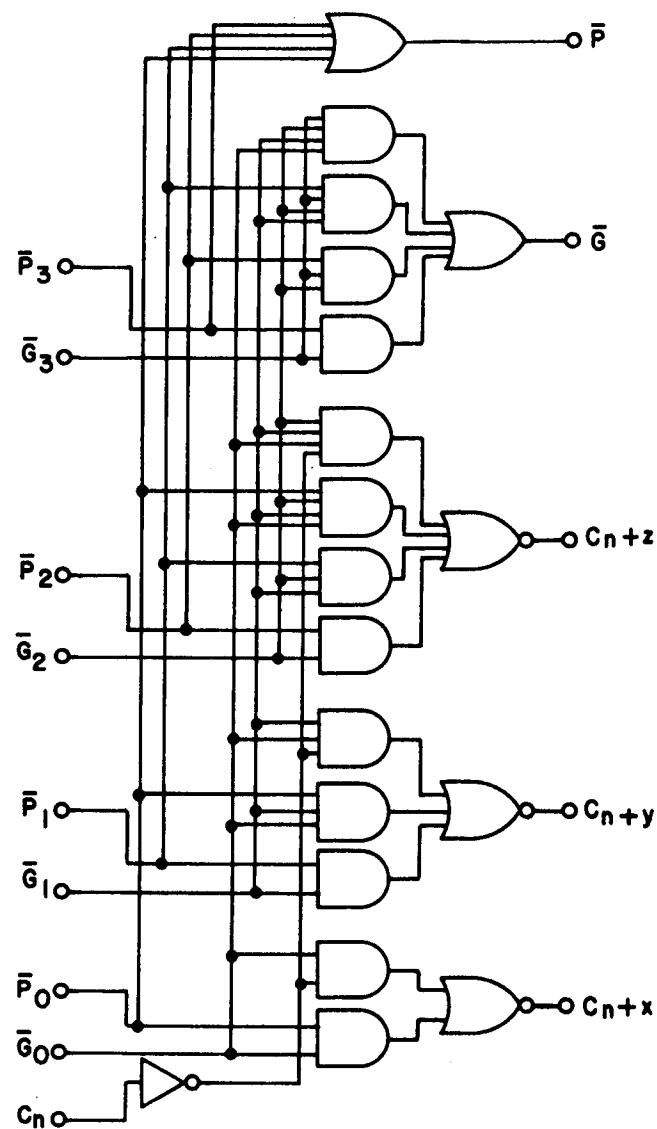
CIRCUITS A AND F

FIGURE 2. Logic diagram for device type 01 - Continued.



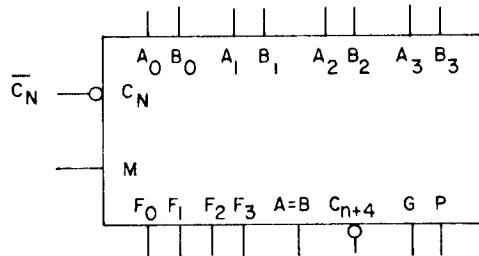
CIRCUITS B, C, D, E AND G

FIGURE 2. Logic diagram for device type 01. - Continued.



CIRCUITS A, B, C, AND D

FIGURE 2. Logic diagram for device type 02



Selection $S_3S_2S_1S_0$	Active high data 3/		
	M = H Logic functions	M = L; Arithmetic operations	
		$C_n = 0$ $\bar{C}_n = 1 = H$	$C_n = 1$ $\bar{C}_n = 0 = L$
0	L L L L	$F = \bar{A}$	$F = A$
1	L L L H	$F = A + \bar{B}$	$F = A + B$
2	L L H L	$F = \bar{A}B$	$F = A + \bar{B}$
3	L L H H	$F = 0$	$F = \text{minus } 1 \text{ (2's compl)}$
4	L H L L	$F = \bar{A}\bar{B}$	$F = A + A\bar{B}$
5	L H L H	$F = \bar{B}$	$F = (A + B) + A\bar{B}$
2/	6	$F = A \oplus B$	$F = A - B - 1$
7	L H H H	$F = A\bar{B}$	$F = A\bar{B} - 1$
8	H L L L	$F = \bar{A} + B$	$F = A + AB$
9	H L L H	$F = \bar{A} \oplus \bar{B}$	$F = A + B$
10	H L H L	$F = B$	$F = (A + \bar{B}) + AB$
11	H L H H	$F = AB$	$F = AB - 1$
12	H H L L	$F = 1$	$F = A + A \quad 1/$
13	H H L H	$F = A + \bar{B}$	$F = (A + B) + A$
14	H H H L	$F = A + B$	$F = (A + \bar{B}) + A$
15	H H H H	$F = A$	$F = A - 1$

1/ Each bit is shifted to the next more significant position.

2/ This device (ALU) can be used as a comparator when placed in the subtract mode (i.e., $S_3S_2S_1S_0$ are at logical levels LHHL respectively) and the following expressions are valid:

Active high data

When C_n is high and C_{n+4} is high, then $A \leq B$

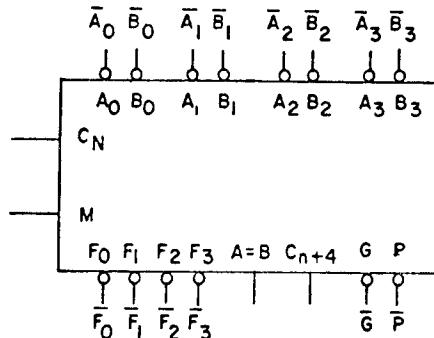
When C_n is low and C_{n+4} is high, then $A < B$

When C_n is high and C_{n+4} is low, then $A > B$

When C_n is low and C_{n+4} is low, then $A \geq B$

3/ The table shown applies for positive logic. If negative logic is used, active high data becomes active low data.

FIGURE 3. Truth tables and logic equations for device type 01.



Selection $S_3 S_2 S_1 S_0$		Active low data 3/		
		M = H Logic functions	M = L; Arithmetic operations	
			$C_n = 0 = L$	$C_n = 1 = H$
0	L L L L	$F = \bar{A}$	$F = A \text{ minus } 1$	$F = A$
1	L L L H	$F = \bar{A}\bar{B}$	$F = AB \text{ minus } 1$	$F = AB$
2	L L H L	$F = \bar{A} + B$	$F = \bar{A}\bar{B} \text{ minus } 1$	$F = A\bar{B}$
3	L L H H	$F = 1$	$F = \text{minus } 1 \text{ (2's compl)}$	$F = \text{zero}$
4	L H L L	$F = \bar{A} + \bar{B}$	$F = A \text{ plus } (A + \bar{B})$	$F = A \text{ plus } (A + \bar{B}) \text{ plus } 1$
5	L H L H	$F = \bar{B}$	$F = AB \text{ plus } (A + \bar{B})$	$F = AB \text{ plus } (A + \bar{B}) \text{ plus } 1$
2/	6	$F = \bar{A} \oplus \bar{B}$	$F = A \text{ minus } B \text{ minus } 1$	$F = A \text{ minus } B$
	7	$F = A + \bar{B}$	$F = A + \bar{B}$	$F = (A + \bar{B}) \text{ plus } 1$
8	H L L L	$F = \bar{A}\bar{B}$	$F = A \text{ plus } (A + B)$	$F = A \text{ plus } (A + B) \text{ plus } 1$
9	H L L H	$F = A \oplus B$	$F = A \text{ plus } B$	$F = A \text{ plus } B \text{ plus } 1$
10	H L H L	$F = B$	$F = \bar{A}\bar{B} \text{ plus } (A + B)$	$F = A\bar{B} \text{ plus } (A + B) \text{ plus } 1$
11	H L H H	$F = A + B$	$F = A + B$	$F = (A + B) \text{ plus } 1$
12	H H L L	$F = 0$	$F = A \text{ plus } A$ 1/	$F = A \text{ plus } A \text{ plus } 1$
13	H H L H	$F = \bar{A}B$	$F = AB \text{ plus } A$	$F = AB \text{ plus } A \text{ plus } 1$
14	H H H L	$F = AB$	$F = \bar{A}\bar{B} \text{ plus } A$	$F = A\bar{B} \text{ plus } A \text{ plus } 1$
15	H H H H	$F = A$	$F = A$	$F = A \text{ plus } 1$

1/ Each bit is shifted to the next more significant position.

2/ This device (ALU) can be used as a comparator when placed in the subtract mode (i.e., $S_3 S_2 S_1 S_0$ are at logical levels LHHL respectively) and the following expressions are valid:

Active low data

When C_n is low and C_{n+4} is low, then $A \leq B$

When C_n is high and C_{n+4} is low, then $A < B$

When C_n is low and C_{n+4} is high, then $A > B$

When C_n is high and C_{n+4} is high, then $A \geq B$

3/ The table shown applies for negative logic. If positive logic is used, active low data becomes active high data.

FIGURE 3. Truth tables and logic equations for device type 01 - Continued.

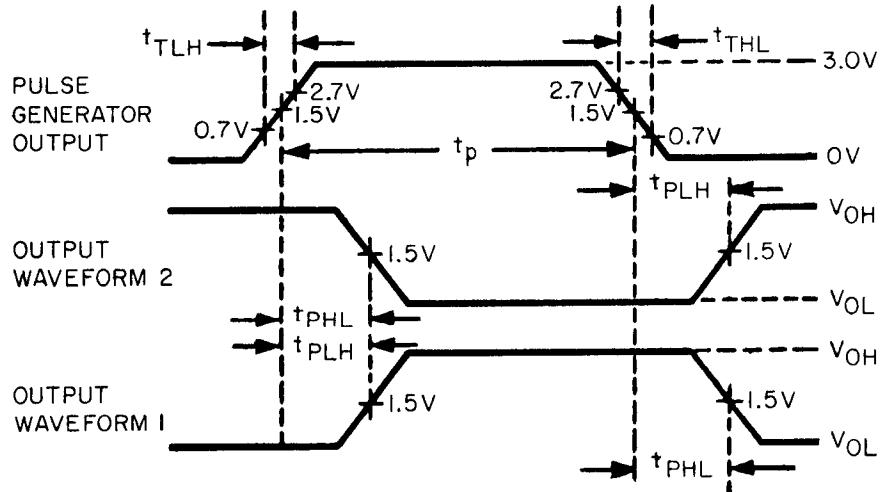
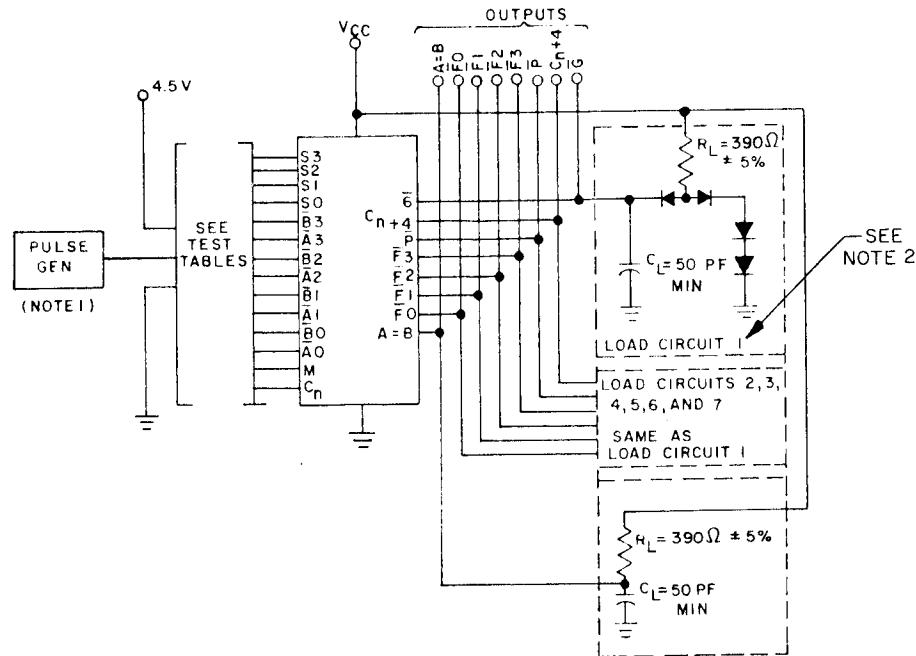
Inputs								Outputs					
C_n	\bar{G}_0	\bar{P}_0	\bar{G}_1	\bar{P}_1	\bar{G}_2	\bar{P}_2	\bar{G}_3	\bar{P}_3	C_{n+x}	C_{n+y}	C_{n+z}	\bar{G}	\bar{P}
X	H	H							L				
L	H	X							L				
X	L	X							H				
H	X	L							H				
X	X	X	H	H					L				
X	H	H	H	X					L				
L	H	X	H	X					L				
X	X	X	L	X					H				
X	L	X	X	L					H				
H	X	L	X	L					H				
X	X	X	X	X	H	H				L			
X	X	X	H	H	H	X				L			
X	H	H	H	X	H	X				L			
L	H	X	H	X	H	X				L			
X	X	X	X	L	X					H			
X	X	X	L	X	X	L				H			
X	L	X	X	L	X	L				H			
H	X	L	X	L	X	L				H			
X	X	X	X	X	H	H					H		
X	X	X	H	H	H	X					H		
X	H	H	H	X	H	X					H		
H	H	X	H	X	H	X					H		
X	X	X	X	L	X					L			
X	X	X	L	X	X	L				L			
X	L	X	X	L	X	L				L			
L	X	L	X	L	X	L				L			
H	X		X		X	X					H		
X	H		X		X	X					H		
X	X		H		X	X					H		
X	X		X		H	X					H		
L	L		L		L	L					L		

H = High voltage level

L = Low voltage level

X = Don't care

FIGURE 3. Truth tables and logic equations for device type 02 - Continued.



NOTES:

1. The pulse generator has the following characteristics: PRR = 1 MHz ±10%, Z_{OUT} ≈ 50 ohms. Pulse width = 200 ns ±10%, t_{TLH} = t_{THL} ≤ 10 ns.
2. Load circuits on a given output are only required where the specific test given in table III indicates "OUT" on that output. Load circuits may otherwise be omitted.
3. C_L includes probe and jig capacitance.
4. All diodes are 1N3064, or equivalent.

FIGURE 4. Waveforms for propagation delay time and test circuit for device type 01.

SUM MODE TEST TABLEFUNCTION INPUTS: $S_0 = S_3 = 4.5 \text{ V}$, $S_1 = S_2 = M = 0\text{V}$

TEST	INPUT UNDER TEST	OTHER INPUT SAME BIT		OTHER DATA INPUTS		OUTPUT UNDER TEST	OUTPUT WAVEFORM
		APPLY 4.5 V	APPLY GND	APPLY 4.5 V	APPLY GND		
t_{PLH1}	\bar{A}_i 1/ \bar{A}_i	\bar{B}_i	None	Remaining \bar{A} and \bar{B}	C_n	Any \bar{F}_i	1
t_{PHL1}		\bar{B}_i	\bar{A}_i	None	Remaining \bar{A} and \bar{B}	C_n	Any \bar{F}_i
t_{PLH1}	\bar{A}_i	\bar{B}_i	None	None	Remaining \bar{A} and \bar{B} , C_n	\bar{P}	1
t_{PHL3}		\bar{B}_i	\bar{A}_i	None	None	Remaining \bar{A} and \bar{B} , C_n	\bar{P}
t_{PLH3}	\bar{A}_i	\bar{B}_i	None	Remaining \bar{B}	Remaining \bar{A} , C_n	\bar{G}	1
t_{PHL3}		\bar{B}_i	\bar{A}_i	None	Remaining \bar{B}	Remaining \bar{A} , C_n	\bar{G}
t_{PLH5}	\bar{A}_i	None	\bar{B}_i	Remaining \bar{B}	Remaining \bar{A} , C_n	\bar{G}	1
t_{PHL5}		\bar{B}_i	None	\bar{A}_i	Remaining \bar{B}	Remaining \bar{A} , C_n	\bar{G}
t_{PLH7}	C_n	None	None	All A	All B	Any \bar{F}_i	1
t_{PHL7}		C_n	None	All A	All B	C_{n+4}	1
t_{PLH9}	C_n	None	None	All A	All B	C_{n+4}	2
t_{PHL9}		\bar{A}_i	None	\bar{B}_i	Remaining \bar{B}	Remaining \bar{A} and C_n	C_{n+4}
t_{PLH11}	\bar{B}_i	None	\bar{A}_i	Remaining \bar{B}	Remaining \bar{A} and C_n	C_{n+4}	2
t_{PHL11}		\bar{B}_i	None	\bar{A}_i	Remaining \bar{B}	Remaining \bar{A} and C_n	C_{n+4}

1/ In \bar{A}_i , \bar{B}_i and \bar{F}_i , $i = 0, 1, 2, \text{ or } 3$.FIGURE 4. Waveforms for propagation delay time and test circuit for device type 01 - Continued.

DIFF MODE TEST TABLE

FUNCTION INPUTS: S1 = S2 = 4.5 V, S0 = S3 = M = 0 V

TEST	INPUT UNDER TEST	OTHER INPUT SAME BIT		OTHER DATA INPUTS		OUTPUT UNDER TEST	OUTPUT WAVEFORM
		APPLY 4.5 V	APPLY GND	APPLY 4.5 V	APPLY GND		
t_{PLH2}	\bar{A}_i 1/ ^{1/}	None	\bar{B}_i	Remaining \bar{A}	Remaining \bar{B}, C_n	Any \bar{F}_i	1
t_{PHL2}	\bar{B}_i	\bar{A}_i	None	Remaining \bar{A}	Remaining \bar{B}, C_n	Any \bar{F}_i	2
t_{PLH4}	\bar{A}_i	None	\bar{B}_i	None	Remaining \bar{A} and \bar{B}, C_n	\bar{P}	1
t_{PHL4}	\bar{B}_i	\bar{A}_i	None	None	Remaining \bar{A} and \bar{B}, C_n	\bar{P}	2
t_{PLH6}	\bar{A}_i	\bar{B}_i	None	None	Remaining \bar{A} and \bar{B}, C_n	\bar{G}	1
t_{PHL6}	\bar{B}_i	None	\bar{A}_i	None	Remaining \bar{A} and \bar{B}, C_n	\bar{G}	2
t_{PLH8}	\bar{A}_i	None	\bar{B}_i	Remaining \bar{A}	Remaining \bar{B}, C_n	$A = B$	1
t_{PHL8}	\bar{B}_i	\bar{A}_i	None	Remaining \bar{A}	Remaining \bar{B}, C_n	$A = B$	2
t_{PLH10}	C_n	None	None	All \bar{A} and \bar{B}	None	C_{n+4}	1
t_{PHL10}							
t_{PLH12}	\bar{A}_i	\bar{B}_i	None	None	Remaining \bar{A} and \bar{B}, C_n	C_{n+4}	2
t_{PHL12}	\bar{B}_i	None	\bar{A}_i	None	Remaining \bar{A} and \bar{B}, C_n	C_{n+4}	1

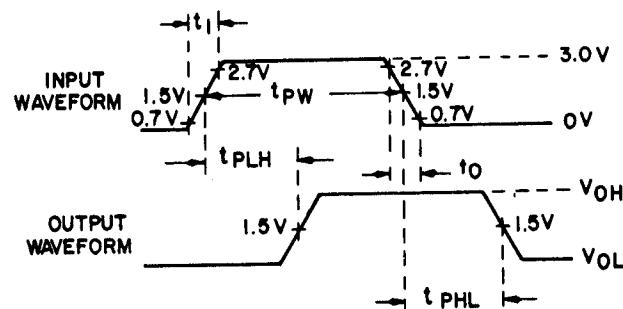
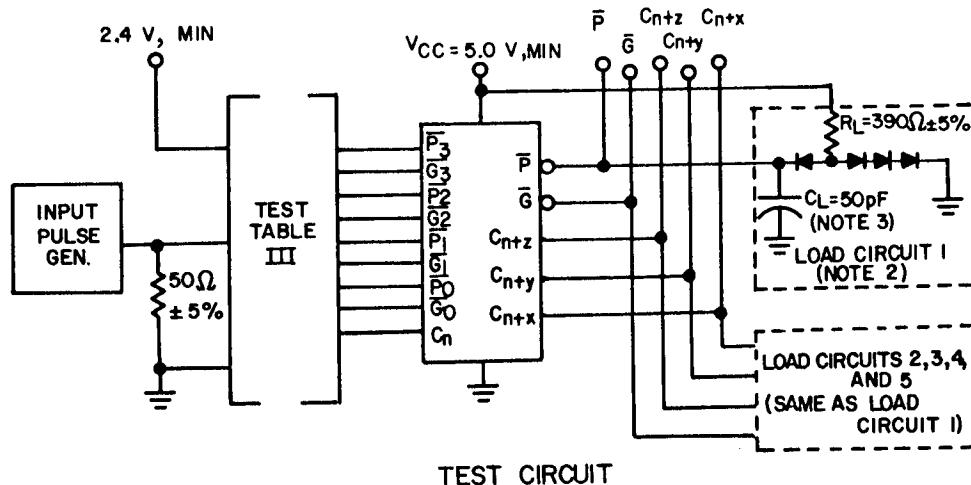
1/ In \bar{A}_i , \bar{B}_i and \bar{F}_i , $i = 0, 1, 2$, or 3 .FIGURE 4. Waveforms for propagation delay time and test circuit for device type 01 - Continued.

LOGIC MODE TEST TABLE

FUNCTION INPUTS: S1 = S2 = M = 4.5 V, S0 = S3 = 0 V

TEST	INPUT UNDER TEST	OTHER INPUT SAME BIT		OTHER DATA INPUTS		OUTPUT UNDER TEST	OUTPUT WAVEFORM
		APPLY 4.5 V	APPLY GND	APPLY 4.5 V	APPLY GND		
t_{PLH13}	\bar{A}_i 1/ \bar{B}_i	None	\bar{B}_i	None	Remaining \bar{A} and \bar{B} , C_n	Any \bar{F}_i	1
t_{PHL13}							
t_{PLH13}	\bar{B}_i	None	\bar{A}_i	None	Remaining \bar{A} and \bar{B} , C_n	Any \bar{F}_i	1
t_{PHL13}							

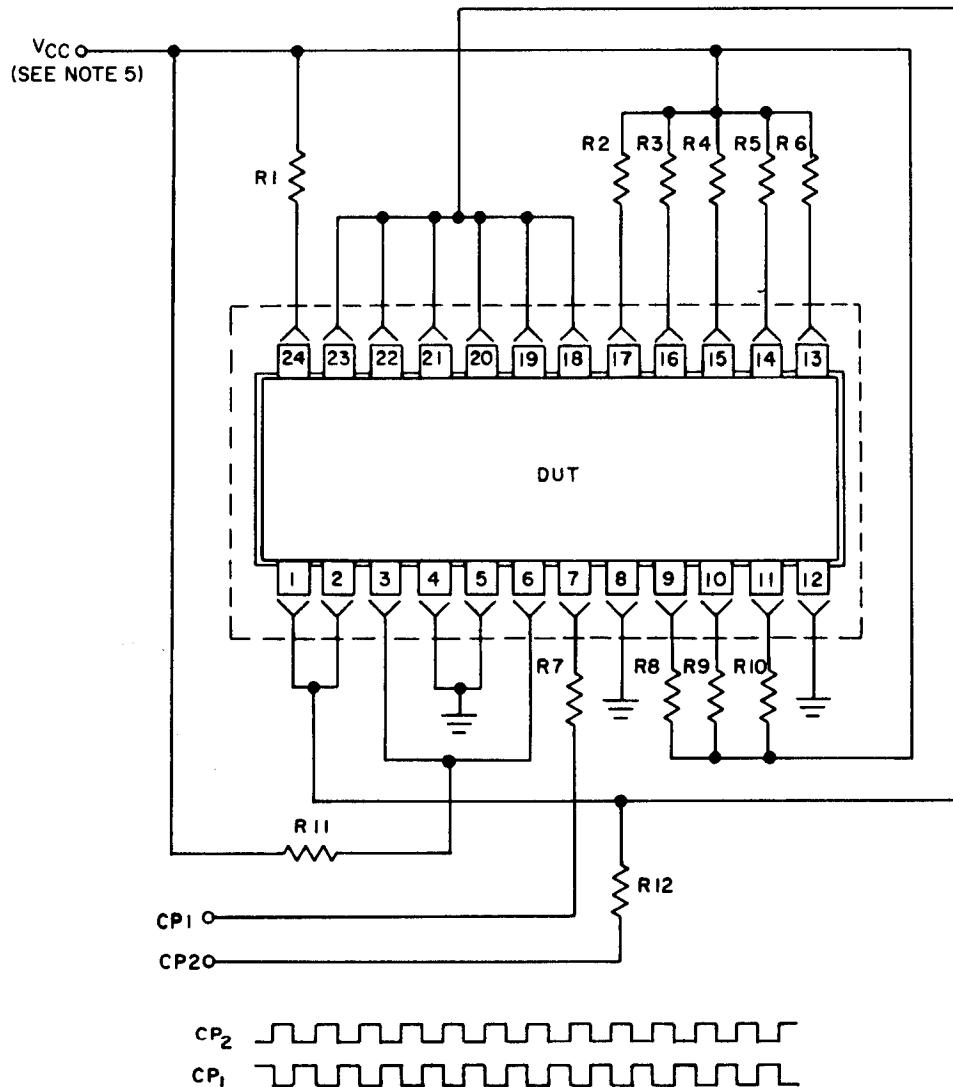
1 In \bar{A}_i , \bar{B}_i and \bar{F}_i , $i = 0, 1, 2$, or 3 .FIGURE 4. Waveforms for propagation delay time and test circuit for device type 01 - Continued.



NOTES:

1. Input pulse characteristics: $t_{PW} = 200 \pm 10\% \text{ ms}$, $\text{PRR} = 1 \text{ MHz}$, $t_0 = t_1 \leq 10 \text{ ns}$, $Z_{OUT} \approx 50 \text{ ohms}$.
2. Load circuits on a given output are only required where the specific test given in table III indicates "OUT" on that output. Load circuits may otherwise be omitted.
3. $C_L = 50 \text{ pF}$ including stray wiring and scope probe.
4. All diodes, 1N3064 or equivalent.

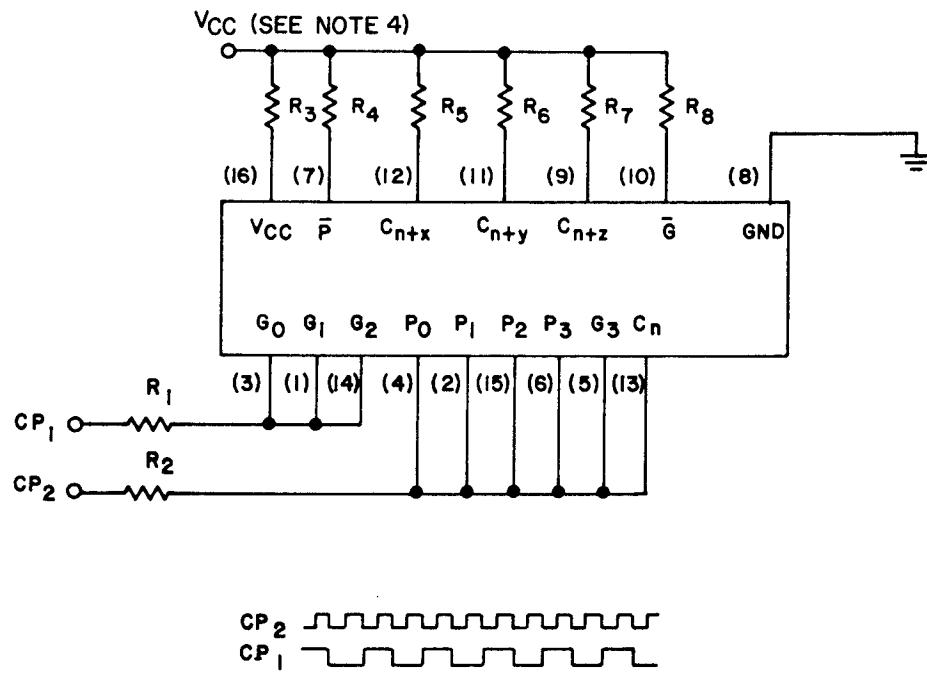
FIGURE 4. Waveforms for propagation delay time and test circuit for device type 02.



NOTES:

1. $R_1 = 5 \text{ ohms} \pm 5\%$.
2. $R_7 = 27 \text{ ohms} \pm 5\%$.
3. R_2 thru R_6 = R_8 thru $R_{11} = 220 \text{ ohms} \pm 5\%$.
4. $R_{12} = 82 \text{ ohms} \pm 5\%$.
5. V_{CC} shall be high enough to insure 5 V minimum at device terminals.
6. $CP_1 = 100 \text{ kHz} \pm 10\%$, duty cycle = $50\% \pm 10\%$, 3 V minimum at device terminals.
7. $CP_2 = 100 \text{ kHz} \pm 10\%$, duty cycle = $50\% \pm 10\%$, 3 V minimum at device terminals.

FIGURE 5. Test circuit for burn-in and life test for device type 01.



NOTES:

1. R₁ = R₂ = 10Ω ±5%.
2. R₃ = 4.7Ω ±5%.
3. R₄ thru R₈ = 220Ω ±5%.
4. V_{CC} shall be high enough to insure 5 V minimum at device terminals.
5. CP₁ 100 kHz ±10%, duty cycle, 50% ±10%, 3 V minimum at device terminals.
6. CP₂ 50 kHz ±10%, duty cycle, 50% ±10%, 3 V minimum at device terminals.

FIGURE 6. Test circuit for burn-in and life test for device type 02.

TABLE III. Group A inspection for device type 01. 1

See notes at end of table for device type 01.

TABLE III. Group A inspection for device type 01¹ - Continued.

See notes at end of table for service type 01.

TABLE III. Group A inspection for device type 01¹ - Continued.

Subgroup	Symbol	MIL-STD-883 method	Case J, K, L, Z	Test No.	Terminal conditions and limits as for subgroup T, except TA = 125°C and -55°C.												Test limits												
					1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	Meas. terminal Min. Max. Unit
7.2/3/ TA = 25°C				88	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	4.5 v		
				89	B	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	All output		
				90	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	H or L as shown		
				91	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B		
				92	B	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				93	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A			
				94	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A			
				95	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				96	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				97	B	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				98	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				99	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				100	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A			
				101	B	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				102	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				103	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				104	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				105	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				106	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				107	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				108	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				109	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				110	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				111	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				112	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
				113	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				114	B	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B			
				115	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A	B	A			
8.2/3/ Same tests, terminal conditions and limits as for subgroup T, except TA = 125°C and -55°C.																													
t _{PHL1} TA = 25°C																													
				3003	116	4.5 v	IN	4.5 v	GND	4.5 v	5.0 v																		
					117																								
					118																								
					119																								
					120																								
					121																								
					122																								
					123																								
					124																								
					125																								
					126																								
					127																								
					128																								
					129																								
					130																								
					131																								

See notes at end of table for device type 01.

TABLE III. Group A inspection for device type 01 1/ - Continued.

Subgroup	Symbol	ML- STD-883 method	Case J, K, L, Z	Test No.	\bar{A}_0	S_0	S_1	S_0	C_n	GND	\bar{F}_0	GND	\bar{F}_3	A=B	\bar{P}	C_{n+4}	\bar{G}	\bar{B}_3	\bar{A}_3	\bar{E}_2	\bar{A}_2	\bar{B}_1	\bar{A}_1	VCC	Meas. terminal	Test limits				
9 $T_A = 25^\circ C$	tPHL2 (Fig 4)	3003	132	GND	IN	GND	4.5 v	GND			OUT	OUT	OUT							GND	4.5 v	GND	4.5 v	IN	4.5 v	5.0 v	5.0 v	ns		
			133	4.5 v							OUT	OUT	OUT																	
			134								OUT	OUT	OUT																	
			135								OUT	OUT	OUT																	
			136								OUT	OUT	OUT																	
			137								OUT	OUT	OUT																	
			138								OUT	OUT	OUT																	
			139								OUT	OUT	OUT																	
	tPLH2		140	GND	IN	4.5 v	4.5 v	GND	GND		OUT	OUT	OUT							GND	4.5 v	GND	4.5 v	IN	4.5 v	4.5 v	4.5 v	ns		
			141								OUT	OUT	OUT																	
			142								OUT	OUT	OUT																	
			143								OUT	OUT	OUT																	
			144								OUT	OUT	OUT																	
			145								OUT	OUT	OUT																	
			146								OUT	OUT	OUT																	
			147								OUT	OUT	OUT																	
	tPHL3		148	4.5 v	IN	4.5 v	GND	GND	4.5 v	GND										GND	GND	GND	GND	4.5 v	IN	4.5 v	4.5 v	ns		
			149																											
			150																											
			151																											
			152																											
			153																											
			154																											
			155																											
	tPLH3		156	4.5 v	IN	4.5 v	GND	GND	4.5 v	GND																				
			157																											
			158																											
			159																											
			160																											
			161																											
			162																											
			163																											
	tPHL4		164	GND	IN	4.5 v	GND	GND	4.5 v	GND																				
			165																											
			166																											
			167																											
			168																											
			169																											
			170																											
			171																											
	tPLH4		172	GND	IN	4.5 v	4.5 v	GND	GND																					
			173																											
			174																											
			175																											
			176																											
			177																											
			178																											
			179																											

See notes at end of table for device type 01.

TABLE III. Group A inspection for device type 011/- Continued.

Subgroup	Symbol	MIL-STD-883 Test No.	Case J, K, L, Z	Test limits																						
				1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
TA = 25 °C	t _{PLH5}	180	GND	IN	4.5 v	GND																				
		181	4.5 v	GND																						
		182																								
		183																								
		184																								
		185																								
		186																								
		187																								
		188	GND	IN	4.5 v	GND																				
		189	4.5 v	GND																						
		190																								
		191																								
		192																								
		193																								
		194																								
		195																								
		196	4.5 v	GND																						
		197																								
		198																								
		199																								
		200																								
		201																								
		202																								
		203																								
		204	4.5 v	GND																						
		205																								
		206																								
		207																								
		208																								
		209																								
		210																								
		211																								
		212	GND	4.5 v	4.5 v	GND	4.5 v	IN	GND	OUT	OUT															
		213	GND	4.5 v	4.5 v	GND	4.5 v	IN	GND	OUT	OUT															
		214	GND	4.5 v																						
		215																								
		216																								
		217																								
		218																								
		219																								
		220																								
		221																								

See notes at end of table for device type 010.

TABLE III. Group A inspection for device type 01 1/ - Continued.

See notes at end of table for device type 01.

TABLE III. Group A inspection for device type 01 1 - Continued.

See notes at end of table for device type 01.

TABLE III. Group A inspection for device type 01 1/ - Continued.

Subgroup	Symbol	Case I, K, L, Z	Test No.	MIL-STD-883 method	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	Test limits			
					A ₀	B ₀	S ₃	S ₂	S ₁	S ₀	C _n	M	GND	F ₀	F ₁	F ₂	GND	F ₃	A=B	P	C _{n+4}	G	B ₃	A ₂	B ₂	A ₁	V _{CC}	Meas. terminal	Max.	Unit		
10 $T_A = 125^\circ C$	tPHL3 (Fig. 4)	314 315 316 317 318 319 320 321	4.5 v GND 4.5 v GND 4.5 v GND 4.5 v GND																									5.0 v	A ₀ to P A ₁ to P A ₂ to P A ₃ to P B ₀ to P B ₁ to P B ₂ to P B ₃ to P	40	ns	
	tPLH3	322 323 324 325 326 327 328 329	4.5 v GND 4.5 v GND 4.5 v GND 4.5 v GND																									4.5 v	A ₀ to P A ₁ to P A ₂ to P A ₃ to P B ₀ to P B ₁ to P B ₂ to P B ₃ to P	7	27	ns
	tPHL4	330 331 332 333 334 335 336 337	GND GND GND GND GND GND GND GND																									4.5 v	A ₀ to P A ₁ to P A ₂ to P A ₃ to P B ₀ to P B ₁ to P B ₂ to P B ₃ to P	7	40	ns
	tPLH4	338 339 340 341 342 343 344 345	GND GND GND GND GND GND GND GND																									4.5 v	A ₀ to P A ₁ to P A ₂ to P A ₃ to P B ₀ to P B ₁ to P B ₂ to P B ₃ to P	7	36	ns
	tPHL5	346 347 348 349 350 351 352 353	4.5 v GND 4.5 v GND 4.5 v GND 4.5 v GND																									4.5 v	A ₀ to G A ₁ to G A ₂ to G A ₃ to G B ₀ to G B ₁ to G B ₂ to G B ₃ to G	7	30	ns
	tPLH5	354 355 356 357 358 359 360	GND 4.5 v GND 4.5 v GND 4.5 v GND 4.5 v																									4.5 v	A ₀ to G A ₁ to G A ₂ to G A ₃ to G B ₀ to G B ₁ to G B ₂ to G B ₃ to G	7	30	ns

See notes at end of table for device type 01.

TABLE III. Group A inspection for device type 01 1/ - Continued.

Subgroup	Symbol	Case J, K, L, Z	Test No.	\overline{E}_0	S_1	S_2	S_3	S_4	S_5	S_6	S_7	S_8	M	\overline{F}_0	F_1	\overline{F}_2	GND	$A-B$	\overline{P}	C_{n+4}	\overline{G}	\overline{B}_3	\overline{A}_2	\overline{B}_1	VCC	Meas			Test limits	
																									terminal	Min	Max	Unit		
$T_A = 125^\circ C$	t_{PHL6}	362	4.5 v	IN	\overline{A}_0	S_1	S_0	S_1	S_0	S_1	S_0	S_1	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_0 to \overline{G}	7	40	ns
	t_{PLH6}	363	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_1 to \overline{G}	7	40	ns
	t_{PHL7}	364	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_2 to \overline{G}	7	40	ns
	t_{PLH7}	365	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_3 to \overline{G}	7	40	ns
	t_{PHL8}	366	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_0 to \overline{G}	7	40	ns
	t_{PLH8}	367	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_1 to \overline{G}	7	40	ns
	t_{PHL9}	368	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_2 to \overline{G}	7	40	ns
	t_{PLH9}	369	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_3 to \overline{G}	7	40	ns
	t_{PHL10}	370	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_0 to \overline{G}	7	40	ns
	t_{PLH10}	371	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_1 to \overline{G}	7	40	ns
	t_{PHL11}	372	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_2 to \overline{G}	7	40	ns
	t_{PLH11}	373	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_3 to \overline{G}	7	40	ns
	t_{PHL12}	374	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_0 to \overline{G}	7	40	ns
	t_{PLH12}	375	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_1 to \overline{G}	7	40	ns
	t_{PHL13}	376	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_2 to \overline{G}	7	40	ns
	t_{PLH13}	377	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_3 to \overline{G}	7	40	ns
	t_{PHL14}	378	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_0 to \overline{G}	7	40	ns
	t_{PLH14}	379	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_1 to \overline{G}	7	40	ns
	t_{PHL15}	380	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_2 to \overline{G}	7	40	ns
	t_{PLH15}	381	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_3 to \overline{G}	7	40	ns
	t_{PHL16}	382	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_0 to \overline{G}	7	40	ns
	t_{PLH16}	383	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_1 to \overline{G}	7	40	ns
	t_{PHL17}	384	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_2 to \overline{G}	7	40	ns
	t_{PLH17}	385	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{B}_3 to \overline{G}	7	40	ns
	t_{PHL18}	386	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_0 to \overline{G}	7	40	ns
	t_{PLH18}	387	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_1 to \overline{G}	7	40	ns
	t_{PHL19}	388	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_2 to \overline{G}	7	40	ns
	t_{PLH19}	389	4.5 v	GND	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND	$4.5 v$	$4.5 v$	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	$5.0 v$	\overline{A}_3 to \overline{G}	7	40	ns
	t_{PHL20}	390	4.5 v	IN	S_1	S_0	S_1	S_0	S_1	S_0	S_1	S_0	GND																	

TABLE III. Group A inspection for device type 01 $\frac{1}{2}$ - Continued.

卷之三

conditions (Pins not designated

conditions (Pins not designated may be H \geq 2.0 V, or L \leq 0.8 V, or open).

Tests shall be performed in sequence:
 Input voltages shown are: $A = 2.0$ volts minimum and $B = 0.8$ volts maximum.
 Output voltages shall be either: (a) $H = 2.44$ v. minimum and $L = 0.4$ v. maximum when using a high speed checker double comparator; or

TABLE III. Group A inspection for device type 02. 1/

Subgroup	Symbol	MIL-STD-883 method	Case E, F		1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits				
			Test No.		\bar{G}_1	\bar{F}_1	\bar{G}_0	\bar{F}_0	\bar{G}_3	\bar{F}_3	\bar{P}	GND	C_{n+Z}	\bar{G}	C_{n+Y}	C_{n+X}	\bar{G}_2	\bar{F}_2	V _{CC}	Meas. terminal	Min	Max	Unit		
$T_A = 25^\circ C$	V_{OH}	3006	1		0.8 V	2.0 V	0.8 V	2.0 V	0.8 V	2.0 V	0.8 V	GND	-0.8 mA	-0.8 mA	0.8 V	0.8 V	0.8 V	4.5 V	2.4 V	\bar{P}	C_{n+Z}	2.0 V	2.4 V	V	
	V_{OL}	3007	2		2.0 V	2.0 V	0.8 V	0.8 V	2.0 V	2.0 V	2.0 V	2.0 V				0.8 V	0.8 V	0.8 V	0.8 V	0.8 V	\bar{P}	C_{n+Z}	0.8 V	0.8 V	V
			3		0.8 V	0.8 V	0.8 V				0.8 V	0.8 V	0.8 V	0.8 V	0.8 V	\bar{P}	C_{n+Z}	0.8 V	0.8 V	V					
			4		0.8 V	0.8 V	0.8 V				0.8 V	0.8 V	0.8 V	0.8 V	0.8 V	\bar{P}	C_{n+Z}	0.8 V	0.8 V	V					
			5		0.8 V	0.8 V	0.8 V				0.8 V	0.8 V	0.8 V	0.8 V	0.8 V	\bar{P}	C_{n+Z}	0.8 V	0.8 V	V					
			6		0.8 V	0.8 V	0.8 V				0.8 V	0.8 V	0.8 V	0.8 V	0.8 V	\bar{P}	C_{n+Z}	0.8 V	0.8 V	V					
			7		0.8 V	0.8 V	0.8 V				0.8 V	0.8 V	0.8 V	0.8 V	0.8 V	\bar{P}	C_{n+Z}	0.8 V	0.8 V	V					
			8		2.0 V	2.0 V	2.0 V				2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	\bar{P}	C_{n+Z}	2.0 V	2.0 V	V					
			9		2.0 V	2.0 V	2.0 V				2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	\bar{P}	C_{n+Z}	2.0 V	2.0 V	V					
			10		2.0 V	2.0 V	2.0 V				2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	\bar{P}	C_{n+Z}	2.0 V	2.0 V	V					
V_{IC}			11		-12 mA																\bar{P}	C_{n+Z}	-1.5		
			12			-12 mA															\bar{P}	C_{n+Z}			
			13				-12 mA														\bar{P}	C_{n+Z}			
			14					-12 mA													\bar{P}	C_{n+Z}			
			15						-12 mA												\bar{P}	C_{n+Z}			
			16							-12 mA											\bar{P}	C_{n+Z}			
			17								-12 mA										\bar{P}	C_{n+Z}			
			18									-12 mA									\bar{P}	C_{n+Z}			
			19										-12 mA								\bar{P}	C_{n+Z}			
			20											-12 mA							\bar{P}	C_{n+Z}			
			21												-12 mA						\bar{P}	C_{n+Z}			
			22													-12 mA					\bar{P}	C_{n+Z}			
			23														-12 mA				\bar{P}	C_{n+Z}			
			24															-12 mA		\bar{P}	C_{n+Z}				
			25																-12 mA	\bar{P}	C_{n+Z}				
			26																	\bar{P}	C_{n+Z}				
			27																	\bar{P}	C_{n+Z}				
I_{IH}			28																	\bar{P}	C_{n+Z}				
			29																	\bar{P}	C_{n+Z}				
			30																	\bar{P}	C_{n+Z}				
			31																	\bar{P}	C_{n+Z}				
			32																	\bar{P}	C_{n+Z}				
			33																	\bar{P}	C_{n+Z}				

See notes at end of device type 02.

TABLE III. Group A inspection for device type 02 1/ - Continued.

Subgroup	Symbol	MIL-STD-883 method	Case E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits			
1 $T_A = 25^\circ C$	I _{H12}	3010	30 CKT A	GND	2.4 V	GND	GND	GND	5.5 V	\bar{P}_1	160 μA												
	I _{H12}		30 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	200														
	I _{H13}		31 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	280														
	I _{H13}		31 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	350														
	I _{H14}		32 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	160														
	I _{H14}		32 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	200														
	I _{H15}		33 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	160														
	I _{H15}		33 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	200														
	I _{H16}		34 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	80														
	I _{H16}		34 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	100														
	I _{H17}		35 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	40														
	I _{H17}		35 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	70														
	I _{H18}		36 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	280														
	I _{H18}		36 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	350														
	I _{H19}		37 CKT A	GND	2.4 V	GND	5.5 V	\bar{G}_1	120														
	I _{H19}		37 CKT B, C	GND	2.4 V	GND	5.5 V	\bar{G}_0	150														
	I _{H20}		38	GND	5.5 V	GND	5.5 V	\bar{G}_1	800														
	I _{H21}		39	GND	5.5 V	GND	5.5 V	\bar{G}_0	400														
	I _{H22}		40	GND	5.5 V	GND	5.5 V	\bar{G}_1	700														
	I _{H23}		41	GND	5.5 V	GND	5.5 V	\bar{G}_0	400														
	I _{H24}		42	GND	5.5 V	GND	5.5 V	\bar{G}_1	400														
	I _{H25}		43	GND	5.5 V	GND	5.5 V	\bar{G}_0	200														
	I _{H26}		44	GND	5.5 V	GND	5.5 V	\bar{G}_1	160														
	I _{H27}		45	GND	5.5 V	GND	5.5 V	\bar{G}_0	700														
	I _{H28}		46	GND	5.5 V	GND	5.5 V	\bar{G}_1	300														
	I _{S4}	3011	47	GND	5.5 V	GND	5.5 V	\bar{G}_0	-40 mA														
	I _{S4}	48	49	GND	5.5 V	GND	5.5 V	\bar{G}_1	65														
	I _{S4}	50	51	GND	5.5 V	GND	5.5 V	\bar{G}_0	35														
	I _{CC12}	3005	52	GND	5.5 V	GND	5.5 V	\bar{G}_1	55														
	I _{CC12}	3005	53	GND	5.5 V	GND	5.5 V	\bar{G}_0	55														
2																							
3																							

See notes at end of device type 02.

TABLE III. Group A inspection for device type 02 1/ - Continued.

Subgroup	Symbol	MIL-STD-883 method	Case E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits	
		Test No.	\bar{G}_1	\bar{F}_1	\bar{G}_0	\bar{F}_0	\bar{G}_3	\bar{F}_3	\bar{G}_2	\bar{F}_2	V_{CC}	C_n	\bar{G}_2	C_{n+X}	C_n	\bar{G}_1	C_{n+Y}	C_{n+Z}	GND	Meas. terminal	Max Unit
7 2/3/ $T_A = 25^\circ C$		54	B	B	B	A	B	B	H	L	4.5 V	B	B	B	B	B	B	B	4.5 V	H or L as shown 4/	
		55	B	A	B	A	B	A	H	L											
		56	A	B	A	B	A	B	H	L											
		57	A	B	A	B	A	B	H	L											
		58	B	A	B	A	B	A	H	L											
		59	A	B	B	A	B	A	H	L											
		60	B	A	B	B	A	B	H	L											
		61	A	B	A	B	B	A	H	L											
		62	B	A	B	B	A	B	H	L											
		63	A	B	A	B	B	A	H	L											
		64	B	A	B	A	B	A	H	L											
		65	A	B	A	A	B	A	H	L											
		66	B	A	B	A	B	A	H	L											
		67																			
8 2/3/			Same tests, terminal conditions and limits as for subgroup 7, except $T_A = 125$ and $-55^\circ C$.																		
9		$T_A = 25^\circ C$	tPLH1 (Fig 4)	68	4.5 V	GND	4.5 V	4.5 V												5.0 V	IN
			tPHL1	69																	
			tPLH1	70																	
			tPHL1	71																	
			tPLH1	72																	
			tPHL1	73																	
			tPLH2	74																	
			tPHL2	75																	
			tPLH2	76																	
			tPHL2	77																	
			tPLH2	78																	
			tPHL2	79																	
			tPLH2	80																	

See notes at end of device type 02.

TABLE III. Group A inspection for device type 02₁ - Continued.

Subgroup	Symbol	MIL-STD-883 method	Case E, F Test No.	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits		
																			Min	Max	Unit	
9 $T_A = 25^\circ C$	tPHL2 tPLH2	3003 (Fig 4)	81	4.5 V	IN	\bar{G}_1	\bar{P}_1	\bar{G}_0	\bar{P}_0	\bar{G}_3	\bar{P}_3	\bar{P}	GND	C_{n+Z}	\bar{G}	$C_{n,Y}$	C_{n+X}	C_n	\bar{G}_2	\bar{P}_2	V _{CC}	
	tPHL2 tPLH2	82	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPHL2 tPLH2	83	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPHL2 tPLH2	84	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPHL2 tPLH2	85	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	86	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	87	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	88	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	89	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	90	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	91	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	92	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	93	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	94	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	95	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	96	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	97	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH3 tPHL3	98	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH4 tPHL4	99	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH4 tPHL4	100	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH4 tPHL4	101	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH4 tPHL4	102	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH5 tPHL5	103	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH5 tPHL5	104	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH5 tPHL5	105	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	
	tPLH5 tPHL5	106	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	4.5 V	GND	4.5 V	4.5 V	GND	4.5 V	OUT	OUT	OUT	OUT	4.5 V	5.0 V	ns	

See notes at end of device type 02.

TABLE III. Group A inspection for device type 02 1/ - Continued.

Subgroup	Symbol	MIL-STD-883 method	Case E, F		1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits				
			Test No.	G ₁	P ₁	G ₀	P ₀	G ₃	P ₃	GND	P	GND	C _{n+Z}	G	C _{n-Y}	C _{n+X}	C _n	G ₂	P ₂	V _{CC}	Meas. terminal	Min	Max	Unit	
9 T _A = 25 °C	tPHL5	3003	107	IN	GND	4.5 V	GND	4.5 V	GND	GND												G ₁ to G	3	25	ns
	tPLH5	108	4.5 V																			G ₂ to G	21	25	
	tPHL5	109																				G ₃ to G	21	25	
	tPLH5	110																				P ₀ to P	21	25	
	tPHL5	111																				P ₀ to P	21	25	
	tPLH6	112																				P ₁ to P	21	25	
	tPHL6	113																				P ₂ to P	21	25	
	tPLH6	114																				P ₃ to P	21	25	
	tPHL6	115																				P ₁ to P	21	25	
	tPLH6	116																				P ₂ to P	21	25	
10 T _A = 125 °C	tPHL1	117																				P ₃ to P	21	25	
	tPLH6	118																				P ₃ to P	21	25	
	tPHL6	119																				P ₃ to P	21	25	
	tPLH1	120																				P ₃ to P	21	25	
	tPHL1	121																				P ₃ to P	21	25	
	tPLH1	122																				P ₃ to P	21	25	
	tPHL1	123																				P ₃ to P	21	25	
	tPLH1	124																				P ₃ to P	21	25	
	tPHL1	125																				P ₃ to P	21	25	
	tPLH2	126																				P ₃ to P	21	25	
	tPHL2	127																				P ₃ to P	21	25	
	tPLH2	128																				P ₃ to P	21	25	
	tPHL2	129																				P ₃ to P	21	25	
	tPLH2	130																				P ₃ to P	21	25	
	tPHL2	131																				P ₃ to P	21	25	
	tPLH2	132																				P ₃ to P	21	25	

See notes at end of device type 02.

TABLE III. Group A inspection for device type 02 2/- Continued.

Subgroup	Symbol	MIL-STD-843 Test No.	Case E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits		
																				Max	Min	Unit
10 $T_A = 125^\circ C$	tPHL2 3003 (Fig 4)	133	4.5 V	IN	4.5 V	GND	4.5 V	4.5 V	GND	GND	C _{n+Z}	OUT	32	3	ns							
	tPLH2	134		IN	IN															25		
	tPHL2	135		IN																32		
	tPLH2	136				GND														25		
	tPHL2	137																		32		
	tPLH3	138																		25		
	tPHL3	139																		25		
	tPLH3	140																		32		
	tPHL3	141																		25		
	tPLH3	142																		32		
	tPHL3	143																		25		
	tPLH3	144																		32		
	tPHL3	145																		25		
	tPLH3	146																		32		
	tPHL3	147																		25		
	tPLH3	148																		32		
	tPHL3	149																		25		
	tPLH4	150																		32		
	tPHL4	151																		26		
	tPLH4	152																		35		
	tPHL4	153																		26		
	tPLH4	154																		35		
	tPHL4	155																		26		
	tPLH5	156																		35		
	tPHL5	157																		26		
	tPLH5	158																		35		
	tPHL5	159																		26		
	tPLH5	160																		35		
	tPHL5	161																		26		
	tPLH5	162																		26		

See notes at end of device type 02.

TABLE III. Group A inspection for device type 02 $\frac{1}{2}$ - Continued.

Subgroup	Symbol	Case E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Test limits		
																			Max	Unit	
10 $T_A = 105^\circ C$	tPHL5 tPLH6 tPHL6 tPHL6 tPHL6 tPHL6 tPHL6 tPHL6	3003 (Fig. 4)	163 164	4.5 4.5	V V	GND GND	4.5 4.5	V V	GND IN	IN IN	GND GND	OUT OUT	$\overline{G}_3 \text{ to } \overline{G}$	3	ns						
			165 166 167 168 169 170 171															$\overline{F}_0 \text{ to } \overline{F}$	3	35	
																		$\overline{F}_1 \text{ to } \overline{F}$	3	35	
																		$\overline{F}_2 \text{ to } \overline{F}$	3	35	
																		$\overline{F}_3 \text{ to } \overline{F}$	3	35	
																		$\overline{P}_3 \text{ to } \overline{P}$	3	35	
																		$\overline{P}_0 \text{ to } \overline{P}$	3	35	
																		$\overline{P}_1 \text{ to } \overline{P}$	3	35	
																		$\overline{P}_2 \text{ to } \overline{P}$	3	26	
																		$\overline{P}_3 \text{ to } \overline{P}$	3	26	

NOTES:

1. Terminal conditions (pins not designated may be $H \geq 2.0$ V, or $L \leq 0.8$ V, or open).
 2. Tests shall be performed in sequence.
 3. Input voltages shown are: $A = 2.0$ volts minimum and $B = 0.8$ volts maximum.
 4. Output voltages shall be either: (a) $H = 2.4$ V, minimum and $L = 0.4$ V, maximum when using a high speed checker single comparator; or (b) $H \geq 1.5$ V when using a high speed checker double comparator; or

4.3 Screening. Screening shall be in accordance with Method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. The following additional criteria shall apply:

- a. Burn-in test (Method 1015 of MIL-STD-883).
 1. Test condition D or E, using the circuit shown on figure 5, or equivalent.
- b. Interim and final electrical test parameters shall be as specified in table II, except interim electrical parameters test prior to burn-in is optional at the discretion of the manufacturer.
- c. Percent defective allowable (PDA) - The PDA for class A devices shall be as specified in MIL-M-38510. The PDA is specified as 10 percent for class B devices based on failures from group A, subgroup 1 test after cooldown as final electrical test in accordance with Method 5004 of MIL-STD-883, and with no intervening electrical measurements. If interim electrical parameter tests are performed prior to burn-in, failures resulting from pre burn-in screening may be excluded from the PDA. If interim electrical parameter tests prior to burn-in are omitted, then all screening failures shall be included in the PDA. The verified failures of group A, subgroup 1 after burn-in divided by the total number of devices submitted for burn-in in that lot shall be used to determine the percent defective for that lot, and the lot shall be accepted or rejected based on the PDA for the applicable device class.
- d. Constant acceleration test (Method 2001 of MIL-STD-883) for case outline J shall be performed using test condition D or E.

4.4 Quality conformance inspection. Quality conformance inspection shall be in accordance with MIL-M-38510.

4.4.1 Group A inspection. Group A inspection shall be in accordance with table I of Method 5005 of MIL-STD-883 and as follows:

- a. Tests shall be as specified in table II.
- b. Subgroups 4, 5 and 6 of table I of Method 5005 of MIL-STD-883 shall be omitted.

4.4.2 Group B inspection. Group B inspection shall be in accordance with table II of Method 5005 of MIL-STD-883.

4.4.3 Group C inspection. Group C inspection shall be in accordance with table III of Method 5005 of MIL-STD-883 and as follows:

- a. End point electrical parameters shall be as specified in table II.
- b. Subgroups 3 and 4 shall be added to the group C inspection requirements for class C devices and shall consist of the tests, conditions and limits specified for subgroups 10 and 11 of group A.
- c. Operating life test (method 1005 of MIL-STD-883) conditions:
 1. Test condition D or E, using the circuit shown on figure 5 or equivalent.
 2. $T_A = 125^\circ\text{C}$, minimum.
 3. Test duration: 1,000 hours, except as permitted by Appendix B of MIL-M-38510.
- d. Constant acceleration test (Method 2001 of MIL-STD-883) for case outline J shall be performed using test condition D or E.

4.4.4 Group D inspection. Group D inspection shall be in accordance with table IV, Method 5005 of MIL-STD-883 and end point electrical parameters shall be as specified in table III.

4.5 Methods of examination and test. Methods of examination and test shall be as specified in the appropriate tables and as follows.

4.5.1 Voltage and current. All voltages given are referenced to the microcircuit ground terminal. Currents given are conventional current and positive when flowing into the referenced terminal.

4.5.2 Life-test cooldown procedure. When devices are measured at 25°C following application of the operating life or burn-in test condition, they shall be cooled to room temperature prior to removal of the bias. Alternately, the bias may be removed during cooling if the case temperature is reduced to room temperature within 30 minutes after removal of the test condition.

4.6 Packaging inspection. The sampling and inspection of the preservation-packaging, packing and container marking shall be in accordance with the requirements of MIL-M-38510, except that the rough handling test shall not apply.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 Notes. The notes specified in MIL-M-38510 are applicable to this specification.

6.2 Intended use. Microcircuits conforming to this specification are intended for use for Government microcircuit applications (original equipment) and logistic purposes.

6.3 Ordering data. Procurement documents should specify the following:

- a. Complete part number (see 1.2).
- b. Requirements for delivery of one copy of the quality conformance inspection data pertinent to the device inspection lot to be supplied with each shipment by the device manufacturer, if applicable.
- c. Requirement for certificate of compliance, if applicable.
- d. Requirements for notification of change of product or process to procuring activity in addition to notification to qualifying activity, if applicable.
- e. Requirements for packaging and packing.
- f. Requirements for failure analysis (including required test condition of Method 5003), corrective action and reporting of results, if applicable.
- g. Requirements for product assurance options.
- h. Requirements for carriers, special lead lengths or lead forming, if applicable.
These requirements shall not affect the part number. Unless otherwise specified, these requirements will not apply to direct purchase by or direct shipment to the Government.
- i. Requirement for JAN marking.

6.4 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-STD-1313, MIL-STD-1331, and as follows:

GND	- - - - -	Electrical ground (common terminal)
V _{IN}	- - - - -	Voltage level at an input terminal
V _{IC}	- - - - -	Input clamp voltage
I _{IN}	- - - - -	Current flowing into an input terminal

6.5 Logistic support. Lead materials and finishes (see 3.3) are interchangeable. Unless otherwise specified, microcircuits procured for Government logistic support will be procured to device class "B" (see 1.2.2) and lead material and finish "C" (see 3.3). Longer lead lengths and lead forming shall not affect the part number.

6.6 Substitutability. Microcircuits covered by this specification will replace the following commercial device types:

<u>Device type</u>	<u>Commercial type</u>	<u>Circuit</u>	<u>Company</u>
01	54181	A	Texas Instruments, Inc.
01	7181	B	National Semiconductor, Corp.
01	54181	C	Motorola, Inc.
01	9341	D	Fairchild Semiconductor
01	54181	E	Advanced Micro Devices, Inc.
01	54181	F	Signetics Corp.
02	9342	A	Fairchild Semiconductor
02	54182	B	Texas Instruments, Inc.
02	54182	C	Motorola, Inc.
02	54182	D	Signetics Corp.

Custodians:

Army - EL
Navy - EC
Air Force - 17

Preparing activity:

Air Force - 17

Review activities:

Army - MI, AR
Air Force - 11, 85, 19, 99
NASA - NA
DLA - ES

(Project 5962-0253)

User activities:

Army - SM
Navy - CG, MC, AS, OS, SH